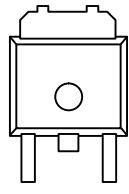


N-Channel 150-V (D-S) 175°C MOSFET

PRODUCT SUMMARY		
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)
150	0.052 @ V _{GS} = 10 V	25
	0.060 @ V _{GS} = 6 V	23

TO-252


Drain Connected to Tab

Top View

Ordering Information:

SUD25N15-52

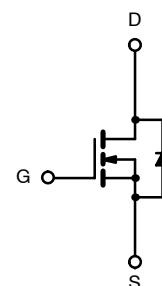
SUD25N15-52—E3 (Lead Free)

FEATURES

- TrenchFET® Power MOSFET
- 175°C Junction Temperature
- PWM Optimized
- 100% R_g Tested

APPLICATIONS

- Primary Side Switch



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	150	V
Gate-Source Voltage		V _{GS}	±20	
Continuous Drain Current (T _J = 175°C) ^b	T _C = 25°C	I _D	25	A
	T _C = 125°C		14.5	
Pulsed Drain Current		I _{DM}	50	
Continuous Source Current (Diode Conduction)		I _S	25	
Avalanche Current		I _{AR}	25	mJ
Repetitive Avalanche Energy (Duty Cycle ≤ 1%)	L = 0.1 mH	E _{AR}	31	
Maximum Power Dissipation	T _C = 25°C	P _D	136 ^b	
	T _A = 25°C		3 ^a	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Junction-to-Ambient ^a	t ≤ 10 sec	R _{thJA}	15	18	°C/W
	Steady State		40	50	
Junction-to-Case (Drain)		R _{thJC}	0.85	1.1	

Notes

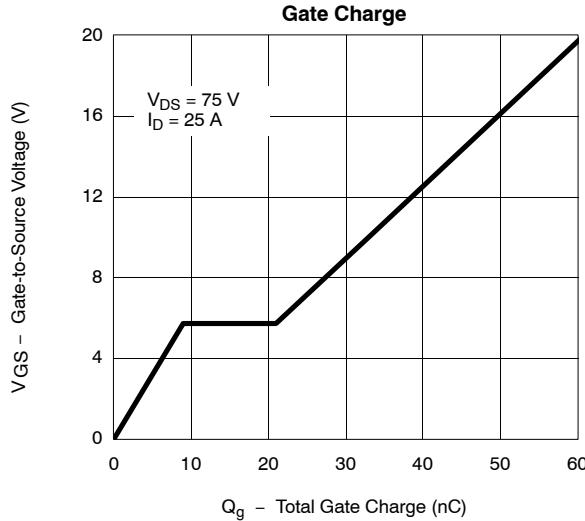
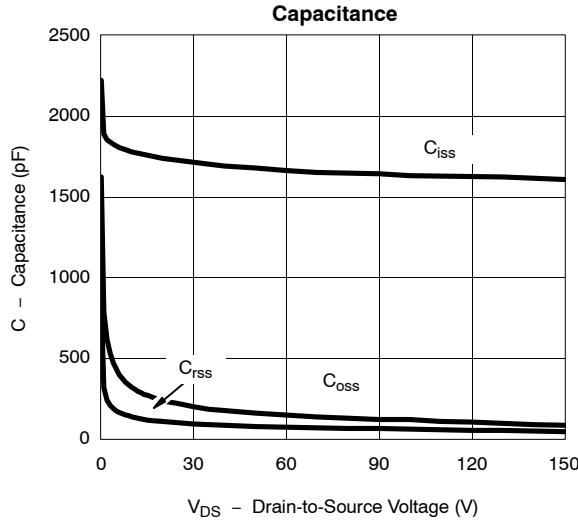
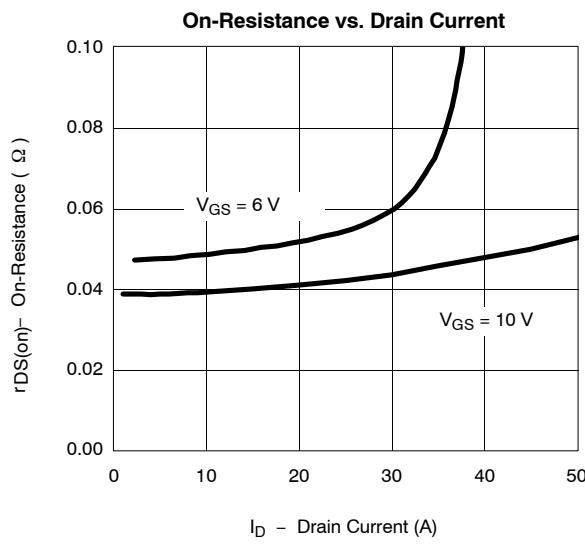
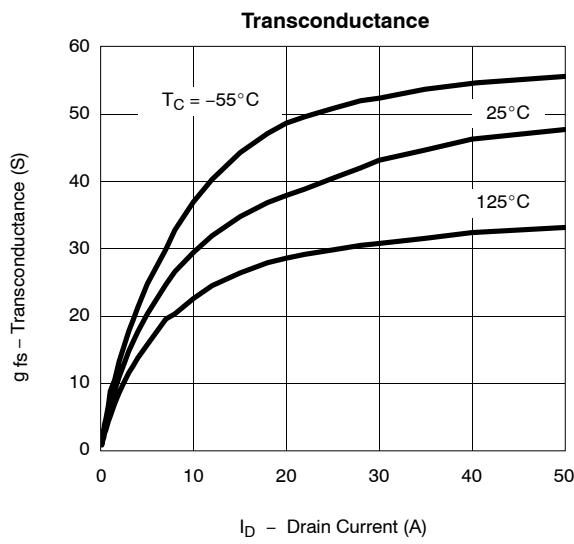
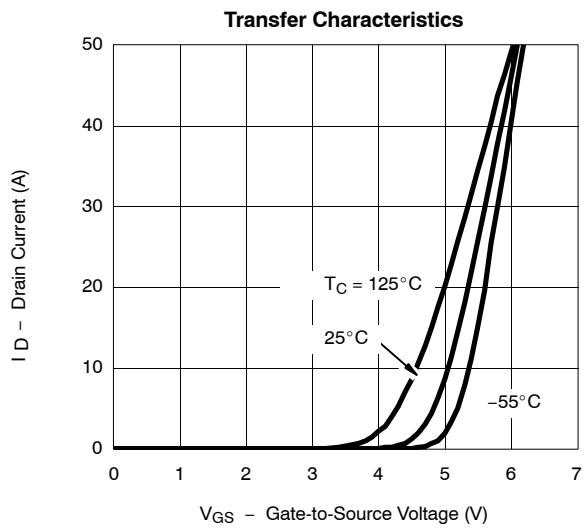
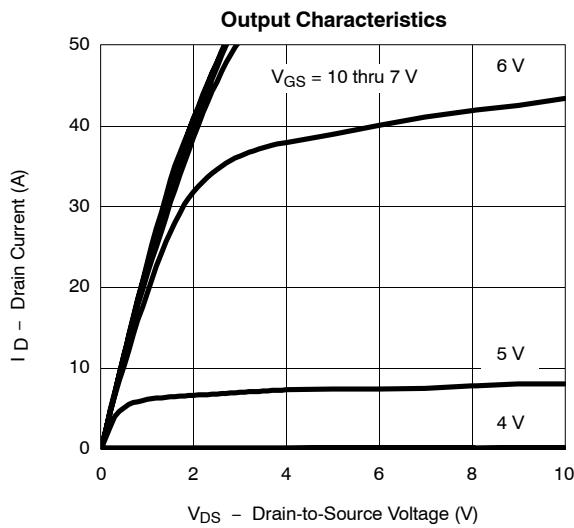
- a. Surface Mounted on 1" x1" FR4 Board.
 b. See SOA curve for voltage derating.

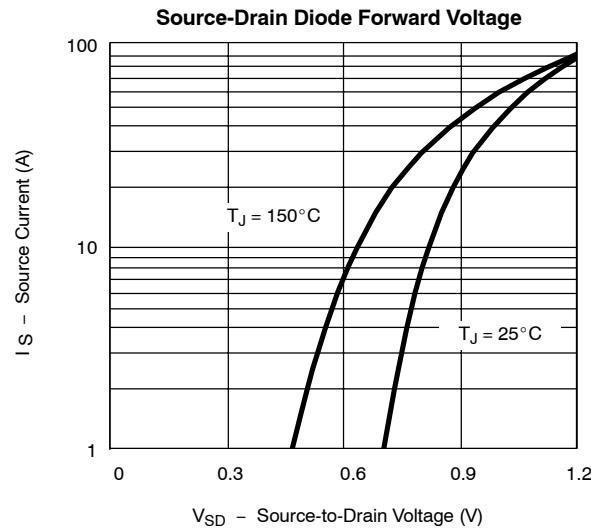
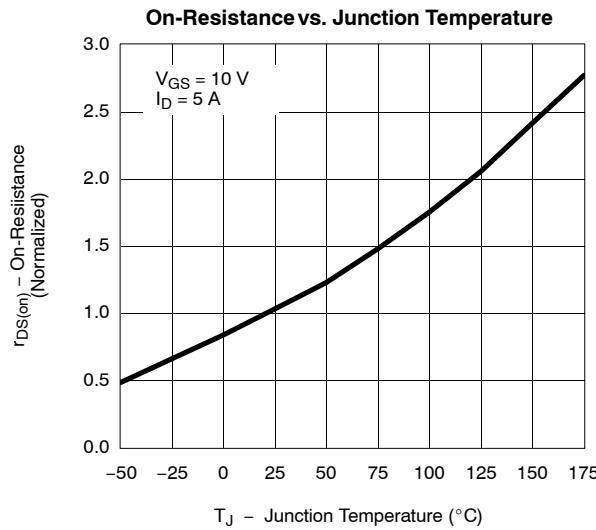
SPECIFICATIONS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0 \text{ V}, I_D = 250 \mu\text{A}$	150			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250 \mu\text{A}$	2		4	
Gate-Body Leakage	I_{GSS}	$V_{\text{DS}} = 0 \text{ V}, V_{\text{GS}} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = 150 \text{ V}, V_{\text{GS}} = 0 \text{ V}$			1	μA
		$V_{\text{DS}} = 150 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 125^\circ\text{C}$			50	
		$V_{\text{DS}} = 150 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 175^\circ\text{C}$			250	
On-State Drain Current ^b	$I_{\text{D}(\text{on})}$	$V_{\text{DS}} = 5 \text{ V}, V_{\text{GS}} = 10 \text{ V}$	50			A
Drain-Source On-State Resistance ^b	$r_{\text{DS}(\text{on})}$	$V_{\text{GS}} = 10 \text{ V}, I_D = 5 \text{ A}$		0.042	0.052	Ω
		$V_{\text{GS}} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 125^\circ\text{C}$			0.109	
		$V_{\text{GS}} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 175^\circ\text{C}$			0.145	
		$V_{\text{GS}} = 6 \text{ V}, I_D = 5 \text{ A}$		0.047	0.060	
Forward Transconductance ^b	g_{fs}	$V_{\text{DS}} = 15 \text{ V}, I_D = 25 \text{ A}$		40		S
Dynamic^a						
Input Capacitance	C_{iss}	$V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = 25 \text{ V}, F = 1 \text{ MHz}$		1725		pF
Output Capacitance	C_{oss}			216		
Reverse Transfer Capacitance	C_{rss}			100		
Total Gate Charge ^c	Q_g	$V_{\text{DS}} = 75 \text{ V}, V_{\text{GS}} = 10 \text{ V}, I_D = 25 \text{ A}$		33	40	nC
Gate-Source Charge ^c	Q_{gs}			9		
Gate-Drain Charge ^c	Q_{gd}			12		
Gate Resistance	R_g		1		3	Ω
Turn-On Delay Time ^c	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = 50 \text{ V}, R_L = 3 \Omega$ $I_D \approx 25 \text{ A}, V_{\text{GEN}} = 10 \text{ V}, R_g = 2.5 \Omega$		15	25	ns
Rise Time ^c	t_r			70	100	
Turn-Off Delay Time ^c	$t_{\text{d}(\text{off})}$			25	40	
Fall Time ^c	t_f			60	40	
Source-Drain Diode Ratings and Characteristic ($T_C = 25^\circ\text{C}$)						
Pulsed Current	I_{SM}				50	A
Diode Forward Voltage ^b	V_{SD}	$I_F = 25 \text{ A}, V_{\text{GS}} = 0 \text{ V}$		0.9	1.5	V
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = 25 \text{ A}, \text{di}/\text{dt} = 100 \text{ A}/\mu\text{s}$		95	140	ns

Notes

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- c. Independent of operating temperature.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**THERMAL RATINGS**